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Substitute for form 1449A/B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)				Complete if Known	
				Application Number	10/801,766
				Filing Date	March 16, 2004
				First Named Inventor	David B Mitzi
				Art Unit	2814
				Examiner Name	Long Pham
Sheet	1	of	1	Attorney Docket Number	20140-00339-US1

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
LP	AA	US-6,379,585-B1	04-30-2002	Vecht et al.	

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ³
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NON PATENT LITERATURE DOCUMENTS						
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.				T ³
LP	CA	"The Use of Soluble Metal-Polyselenide Complexes as Precursors to Binary and Ternary Solid Metal Selenides" by Dhingra et al., Mat. Res. Soc. Symp. Proc. Vol. 180, 1990, pages 825-830				
	CB	"Successive ionic layer adsorption and reaction (SILAR) method for the deposition of large area (~10cm ²) tin disulfide (SnS ₂) thin films" Sankpal et al., Materials Research Bulletin 35 (2000) pages 2027-2035				
	CC	"Polycrystalline CdSe Films for Thin Film Transistors" Van Calster et al., Journal of Crystal Growth 86 (1988) pages 924-928				
	CD	"Preparation of Thin-Film Transistors with Chemical Bath Deposited CdSe and CdS Thin Films" Gan et al., IEEE Transactions on Electron Devices, Vol. 49, No. 1, January 2002, pages 15-18				
	CE	"Spin-coated amorphous chalcogenide films" Chern et al., J. Appl. Phys. 53 (10), October 1982, pages 6979-6982				
	CF	"Spin-Coating of MoS ₂ Thin Films" Pütz et al., Institut für Neue Materialien - INM, Department of Coating Technology, Im Stadtwald, Geb. 43, D-66123 Saarbrücken, Germany, 6 pages				
	CG	"Solution processed CdS thin film transistors" Schön et al., Thin Solid Films 385 (2001) pages 271-274				
	CH	"A Novel Method for the Preparation of Inorganic Sulfides and Selenides" I. Binary Materials and Group II-VI Phosphors, Davies et al., Journal of the Electrochemical Society, 147 (2), pages 765-771 (2000)				
	CI	"All-Inorganic Field Effect Transistors Fabricated by Printing" Ridley et al., October 22, 1999, Vol. 286, Science, pages 746-749				
	CJ	"A Method for the Clean Syntheses of Sulfides/Selenides" II. Ternary Sulfides/Selenides, Marsh et al., Journal of the Electrochemical Society, 148 (7) pages D89-D93 (2001)				
	CK	"Electrical Characterization of 2H-SnS ₂ Single Crystals Synthesized by the Low Temperature Chemical Vapor Transport Method" Shibata et al., J. Phys. Chem. Solids Vol. 52, No. 3, pages 551-553, 1991				

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Examiner Signature	Long Pham	Date Considered	12/8/05
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